TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC74LVX138F,TC74LVX138FN,TC74LVX138FT

3-to-8 Line Decoder

The TC74LVX138F/ FN/ FT is a high-speed CMOS 3-to-8 line decoder fabricated with silicon gate CMOS technology. Designed for use in 3-V systems, it achieves high-speed operation while maintaining the CMOS low power dissipation.

This device is suitable for low-voltage and battery operated systems.

When the device is enabled, 3 Binary Select inputs (A, B and C) determine which one of the outputs ($\overline{Y}0 \cdot \overline{Y}7$) will go low. When enable input G1 is held low or either $\overline{G}2A$ or $\overline{G}2B$ is held high, decoding function is inhibited and all outputs go high.

 \overline{G} 1, \overline{G} 2A, and \overline{G} 2B inputs are provided to ease cascade connection and for use as an address decoder for memory systems.

An input protection circuit ensures that 0 to 5.5V can be applied to the input pins without regard to the supply voltage. This device can be used to interface 5V to 3V systems and two supply systems such as battery back up. This circuit prevents device destruction due to mismatched supply and input voltages.

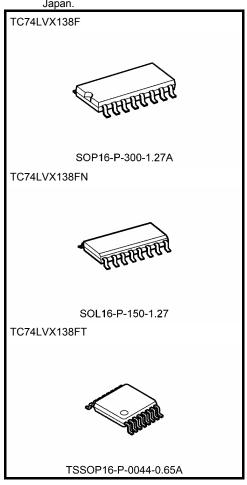
Features

- High-speed: $t_{pd} = 5.5 \text{ ns (typ.) (VCC} = 3.3 \text{ V)}$
- Low power dissipation: $I_{CC} = 4 \mu A \text{ (max) (Ta} = 25 ^{\circ}\text{C)}$
- Input voltage level: $V_{IL} = 0.8 \text{ V (max)} (V_{CC} = 3 \text{ V})$

$$V_{IH} = 2.0 \text{ V (min) (V}_{CC} = 3 \text{ V)}$$

- Power-down protection provided on all inputs
- Balanced propagation delays: $t_{pLH} \simeq t_{pHL}$
- Pin and function compatible with 74HC138

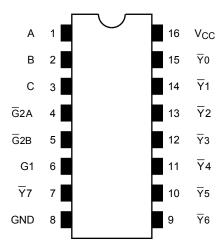
Note: xxxFN (JEDEC SOP) is not available in Japan.



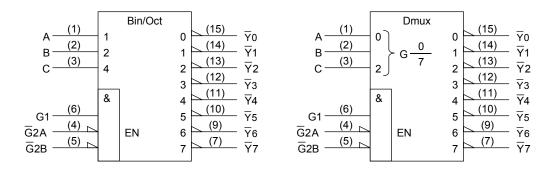
Weight

SOP16-P-300-1.27A : 0.18 g (typ.) SOL16-P-150-1.27 : 0.12 g (typ.) TSSOP16-P-0044-0.65A : 0.06 g (typ.)

Pin Assignment (top view)



IEC Logic Symbol

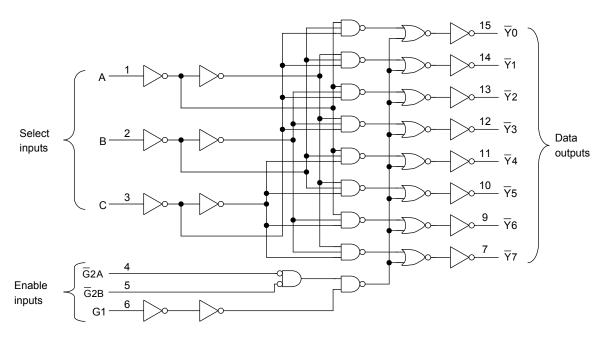


Truth Table

	Inputs						Outputs							
Enable		Select			₹0	<u>7</u> 1	_ Y2		<u>7</u> 4		<u>7</u> 6	_ Y7	Selected Output	
G1	G ₂ A	G ₂ B	С	В	Α	10	11	12	13	14	13	10	1 /	
L	Х	Х	Х	Х	Х	Н	Н	Н	Н	Н	Н	Н	Н	None
Х	Н	X	X	Х	Х	Η	Η	Н	Н	Η	Н	Η	Н	None
Х	Х	Н	Х	Х	Х	Н	Н	Н	Н	Н	Н	Н	Н	None
Н	L	L	L	L	L	L	Н	Н	Н	Н	Н	Н	Н	₹0
Н	L	L	L	L	Н	Н	L	Н	Н	Н	Н	Н	Н	₹1
Н	L	L	L	Н	L	Н	Н	L	Н	Н	Н	Н	Н	Ÿ2
Н	L	L	L	Н	Н	Н	Н	Н	L	Н	Н	Н	Н	Y 3
Н	L	L	Н	L	L	Н	Н	Н	Н	L	Н	Н	Н	Y 4
Н	L	L	Н	L	Н	Н	Н	Н	Н	Н	L	Н	Н	Ȳ5
Н	L	L	Н	Н	L	Н	Н	Н	Н	Н	Н	L	Н	₹6
Н	L	L	Н	Н	Н	Н	Н	Н	Н	Н	Н	Н	L	Ÿ7

X: Don't care

System Diagram



Absolute Maximum Ratings (Note)

Characteristics	Symbol	Rating	Unit
Supply voltage range	V_{CC}	-0.5 to 7.0	V
DC input voltage	V _{IN}	-0.5 to 7.0	٧
DC output voltage	V _{OUT}	-0.5 to V_{CC} + 0.5	٧
Input diode current	l _{IK}	-20	mA
Output diode current	lok	±20	mA
DC output current	lout	±25	mA
DC V _{CC} /ground current	Icc	±75	mA
Power dissipation	P _D	180	mW
Storage temperature	T _{stg}	-65 to 150	°C

Note: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Operating Ranges (Note)

Characteristics	Symbol	Rating	Unit
Supply voltage	V _{CC}	2.0 to 3.6	٧
Input voltage	V _{IN}	0 to 5.5	٧
Output voltage	V _{OUT}	0 to V _{CC}	٧
Operating temperature	T _{opr}	-40 to 85	°C
Input rise and fall time	dt/dv	0 to 100	ns/V

Note: The operating ranges must be maintained to ensure the normal operation of the device. Unused inputs must be tied to either VCC or GND.



Electrical Characteristics

DC Characteristics

Character	Symbol Test Condition				Ta = 25°C			Ta = -40 to 85°C		Unit	
					V _{CC} (V)	Min	Тур.	Max	Min	Max	
			_		2.0	1.5	_	_	1.5	_	
	H-level	V _{IH}			3.0	2.0	_	_	2.0	_	
Input voltage					3.6	2.4	_	_	2.4	_	Unit V
input voltage			_		2.0	_	_	0.5	_	0.5	v
	L-level	V _{IL}			3.0	_	_	0.8	_	0.8	
					3.6	_	_	0.8	_	0.8	
			V _{IN} = V _{IH} or V _{IL}	$I_{OH} = -50 \mu A$	2.0	1.9	2.0	_	1.9	_	
	H-level	VoH		I _{OH} = -50 μA	3.0	2.9	3.0	_	2.9	_	
Output voltage				I _{OH} = -4 mA	3.0	2.58	_	_	2.48	_	\/
Output voltage			V _{IN} = V _{IH} or V _{IL}	I _{OL} = 50 μA	2.0	_	0	0.1	_	0.1	V
	L-level	V _{OL}		I _{OL} = 50 μA	3.0	_	0	0.1	1 — 0.1	0.1	-
				I _{OL} = 4 mA	3.0	_	_	0.36	_	0.44	
Input leakage cur	I _{IN}	V _{IN} = 5.5 V or GND		3.6	_	_	±0.1	_	±1.0	μА	
Quiescent supply	current	I _{CC}	V _{IN} = V _{CC} or GND		3.6	_		4.0	_	40.0	μА



AC Characteristics (input: $t_r = t_f = 3$ ns)

Characteristics	Symbol	Test Condition			-	Га = 25°0		Ta = -40 to 85°C		Unit
			V _{CC} (V)	C _L (pF)	Min	Тур.	Max	Min	Max	
	t		2.7	15	_	7.1	13.8	1.0	16.5	ns
Propagation delay time	t _{pLH}		2.1	50	_	9.6	17.3	1.0	20.0	
$(A, B, C-\overline{Y})$	+	_	3.3 ± 0.3	15	_	5.5	8.8	1.0	10.5	
	t _{pHL}		3.3 ± 0.3	50	_	8.0	12.3	1.0	14.0	
	+		2.7	15	_	8.7	16.3	1.0	19.5	ns
Propagation delay time	t _{pLH}			50	_	11.2	19.8	1.0	23.0	
(G1- \overline{Y})	+	_	3.3 ± 0.3	15	_	6.8	10.6	1.0	12.5	115
	t _{pHL}		3.3 ± 0.3	50	_	9.3	14.1	1.0	16.0	
	t _{pLH}		2.7 3.3 ± 0.3	15	_	8.8	16.0	1.0	18.5	ns
Propagation delay time				50	_	11.3	19.5	1.0	22.0	
(G 2 - Y)		_		15	_	6.9	10.4	1.0	11.5	
				50	_	9.4	13.9	1.0	15.0	
Output to output skew	t _{osLH}	(Note 1)	2.7	50	_	_	2.5	_	2.5	
Output to output skew	t _{osHL}	(Note 1)	3.3 ± 0.3	50	_	_	2.5	_	2.5	ns
Input capacitance	C _{IN}			(Note 2)	_	4	10	_	10	pF
Power dissipation capacitance	C _{PD}			(Note 3)		34	_	_	_	pF

Note 1: Parameter guaranteed by design.

 $(t_{OSLH} = |t_{PLHm} - t_{PLHn}|, \ t_{OSHL} = |t_{PHLm} - t_{PHLn}|)$

Note 2: Parameter guaranteed by design.

Note 3: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption.

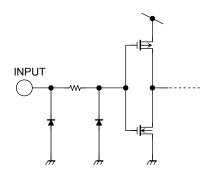
Average operating current can be obtained by the equation:

 $I_{CC (opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}$

Noise Characteristics (Ta = 25°C, input: $t_r = t_f = 3 \text{ ns}$, $C_L = 50 \text{ pF}$)

Characteristics	Symbol	mbol Test Condition		Тур.	Limit	Unit
Oviet autout magains and drag arried V	\ /		V _{CC} (V)		0.5	\ /
Quiet output maximum dynamic V _{OL}	V _{OLP}	_	3.3		0.5	V
Quiet output minimum dynamic V _{OL}	V _{OLV}	_	3.3	_	-0.5	V
Minimum high level dynamic input voltage $V_{\mbox{\scriptsize IH}}$	V _{IHD}	_	3.3	_	2.0	V
Maximum low level dynamic input voltage V_{IL}	V _{ILD}	_	3.3	_	0.8	V

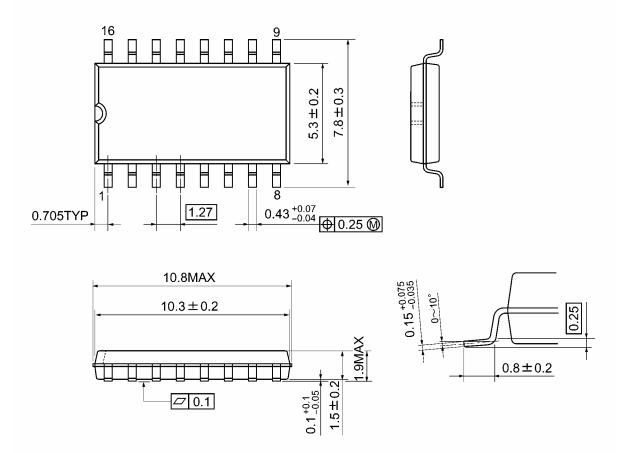
Input Equivalent Circuit



Package Dimensions

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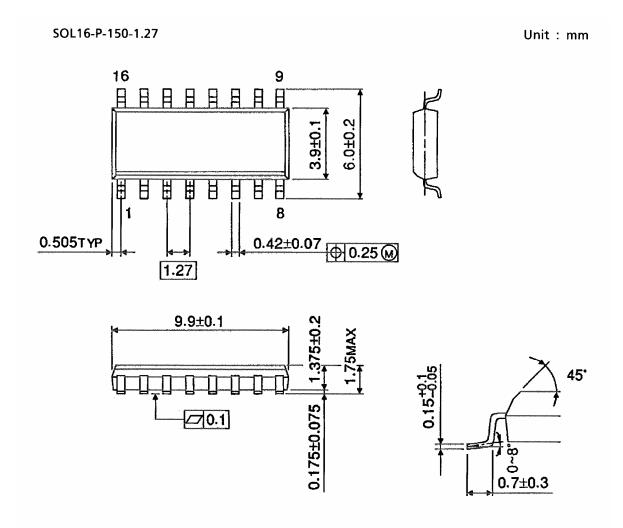
SOP16-P-300-1.27A Unit: mm



Weight: 0.18 g (typ.)

Package Dimensions (Note)

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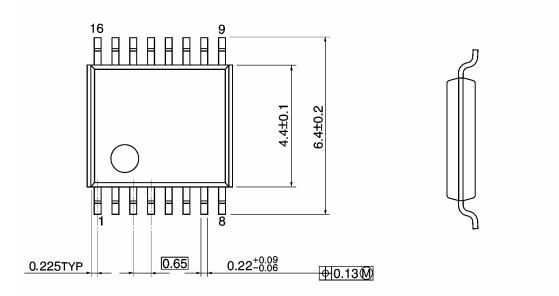


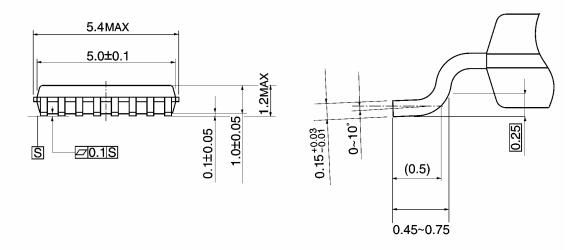
Note: This package is not available in Japan.

Weight: 0.12 g (typ.)

Package Dimensions

TSSOP16-P-0044-0.65A Unit: mm





Weight: 0.06 g (typ.)

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20070701-EN GENERAL

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